

Application Data Sheet

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Application Information

Title Line One: Epitaxial Silicon Wafer  
Total Drawing Sheets: 4  
Formal Drawings: Yes  
Application Type: Utility  
Docket Number: 86396

Representative Information

Registration Number One: 24,003  
Registration Number Two: 22,839  
Registration Number Three: 28,903  
Registration Number Four: 27,429  
Registration Number Five: 25,060  
Registration Number Six: 22,053  
Registration Number Seven: 27,466

Registration Number Eight 29,434  
Registration Number Nine: 29,054  
Registration Number Ten: 29,381  
Registration Number Eleven: 34,044  
Registration Number Twelve: 27,600  
Registration Number Thirteen: 34,137  
Registration Number Fourteen: 39,724  
Registration Number Fifteen: 37,963  
Registration Number Sixteen: 41,050  
Registration Number Seventeen: 34,217

This application is based on application

Application One: PCT/JP00/04216

Filing Date: June 26, 2000

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Japanese application no. 241187/1999

Filing Date: August 27, 1999